



44 FARRAND STREET
BLOOMFIELD, NJ 07003
(973) 748-5089

NTE1254

Integrated Circuit

Phase-Lock Loop (PLL) Frequency

Synthesizer for CB

Features:

- Programmable Divider – Divided by 3 to 255
- 10-Bit Divider
- Phase Detector
- Reference Oscillation Circuit
- On-Chip Filter Amplifier
- Code Converter
- Only two or three crystals required for CB radio AM frequency selection
- Unlocked signals are detected at instant stop “IS” terminal
- Two type program mode can be selected to change input mode level
 - M: Low level . Binary code input enables, divided by 3 to 255
 - M: High level . BCD code enables that the data at P₁ to P₆ port is offset 90 by code converter
- Internal active filter amplifier has a long holding time due to very high input impedance characteristics of the CMOS–this is to obtain very good spurious response.
- Output signal of the “I” can be used to stop the spurious radiation when the channel selector makes misprogramming such as rotary switch's lose contact.
- High speed and low power consumption due to CMOS
- Single power supply and fully TTL compatible: V_{DD} = 5 ± 0.5 Volts
- Operating Temperature: T_A = -30° to 65°C
- Pull down resistors installed in program and mode switch inputs

Absolute Maximum Ratings:

Supply Voltage	-0.3 to +6.0V
Input Voltage	-0.3 to +6.0V
Operating Temperature Range, T _{opr}	-35° to +75°C
Storage Temperature Range, T _{stg}	-55° to +125°C

Electrical Characteristics: ($T_A = -35^\circ$ to $+75^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Power Supply	V_{DD}		4.5	5.0	5.5	V
Total Current	I_{DD}	$f = 0$	—	—	10	mA
High Level Input Voltage	V_{IH}	All Inputs	$0.8V_{DD}$	—	V_{DD}	V
Low Level Input Voltage	V_{IL}	All Inputs	-0.3	—	$0.2V_{DD}$	V
High Level Output Voltage	V_{OH}	All Outputs Except D ₂ , $I_O = -0.3\text{mA}$, $V_{DD} = 4.5\text{V}$	$0.85V_{DD}$	—	V_{DD}	V
		$I_O = -0.15\text{mA}$, $V_{DD} = 4.5\text{V}$	$0.85V_{DD}$	—	V_{DD}	V
Low Level Output Voltage	V_{OL}	All Inputs, $I_O = 0.5\text{mA}$, $V_{DD} = 4.5\text{V}$	-0.3	—	$0.15V_{DD}$	V
Leakage Current	I_L	EO (Floating), AI $T_A = +25^\circ\text{C}$	—	1.0	—	nA
Input Capacitance	C_i	PI, FD, FP, X ₁ , $V_i = 0$	—	—	10	pF
Maximum Frequency Response	$f_{d\max}$	X ₁ – X ₂ , Divider	11	—	—	MHz
	$f_{p\max}$	Programmable Divider	—	2	—	MHz

Pin Connection Diagram

